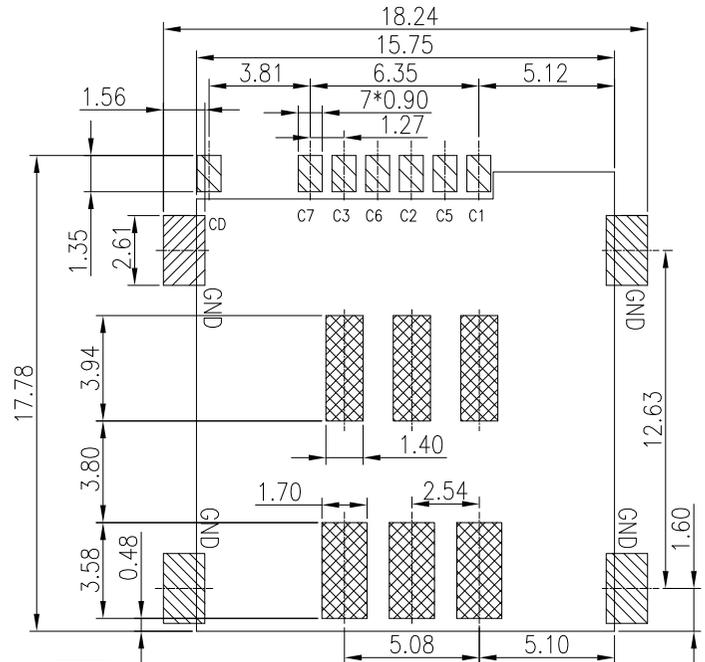
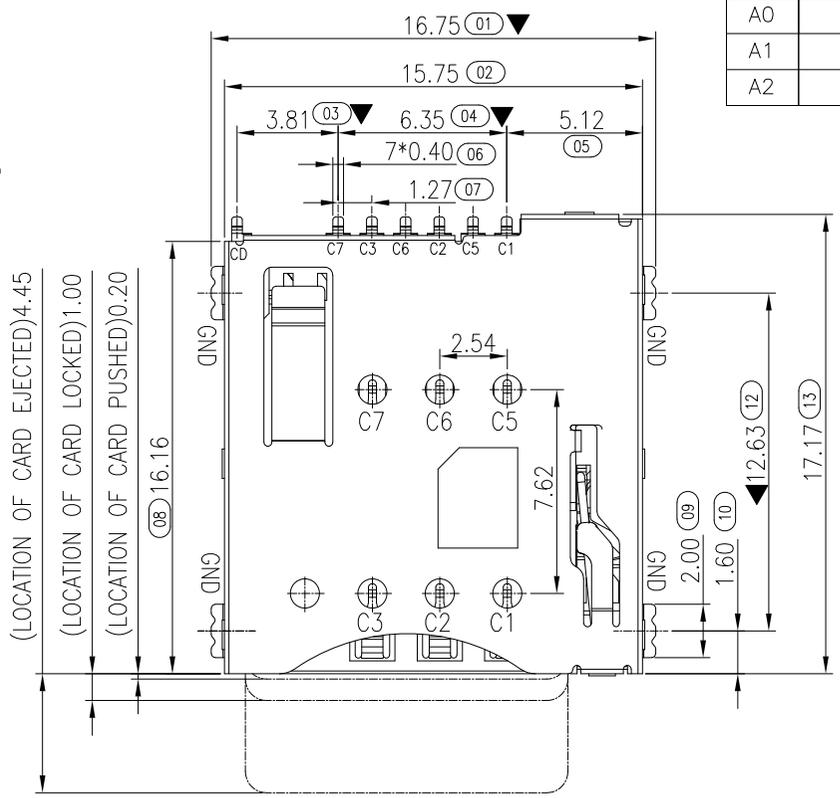
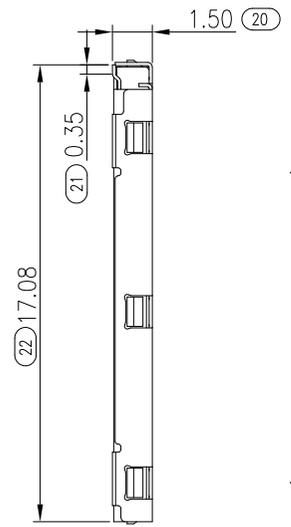
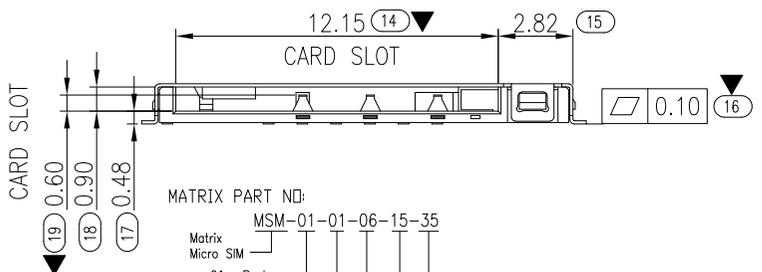
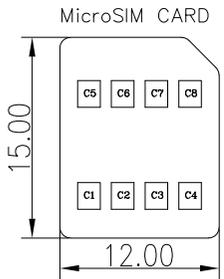


# GP Component

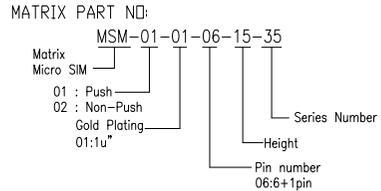
REV.	ECN NO.	LOCATIONS	DESCRIPTION	DATE	DESIGN
A0			Initial	2017/05/05	Phebe Su
A1			Change	2018/06/15	Phebe Su
A2			Correct drawing	2019/03/26	Summer Wang



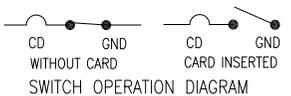
PAD AREA  
 KEEP OUT AREA  
**RECOMMENDED P.C.B LAYOUT**  
 COMPONENT SIDE(TOLERANCE ±0.05)



- NOTES:
- SPECIALITY:
    - Rated current:1.0A
    - Rated voltage:30V
    - Contact Resistance:50mΩ MAX
    - Insulation Resistance:1000MΩ MIN 500V DC
    - Dielectric withstanding voltage: 500V AC.
    - Solder ability:250±5°C · 5±0.5s.
    - Durability:1500 Cycles Min.
    - Operating condition:Temperature-40°C~+85°C :



ELECTRIC FUNCTION	DETECT SWITCH
WITHOUT CARD	CLOSED
CARD INSERTED	OPEN



NO	Description	Dosage	Material	Color/plating
7	LINK	1PC	STEEL	PLATE WITH NICKEL
6	SPRING	1PC	SWP-B	PLATE WITH NICKEL
5	Slide	1PC	HI-TEMP THERMOPLASTIC	UL94V-0 BLACK
4	Shell	1PC	STEEL	SMT AREA:GOLD PLATED
3	CD Switch	1PC	COPPER ALLOY	CONTACT AREA:GOLD PLATED
2	Data Contact	1PC	COPPER ALLOY	CONTACT AREA:GOLD PLATED
1	Housing	1PC	HI-TEMP THERMOPLASTIC	UL94V-0 BLACK

Pin No.	NAME
C1	VCC
C2	RST
C3	CLK
C5	GND
C6	VPP
C7	I/O

Matrix Electronics Co.,Ltd

**TOLERANCE:**  
 X:X ±0.30  
 X:XX ±0.20  
 X:XXX ±0.10  
 ANGLE: ±3°

**DESIGN BY :** Summer Wang  
**DATE :** 2019/03/26  
**CHECKED BY:** Vicky Hsieh  
**DATE :** 2019/03/26  
**APPROVED BY1:** Richard Hsieh  
**DATE :** 2019/03/26  
**APPROVED BY2:** Richard Hsieh  
**DATE :** 2019/03/26

**PART NAME:** Micro SIM PUSH H1.5  
**PART NO.:** MSM-01-01-06-15-35  
**MOLD NO.:** NA  
**DRAW NO.:**  
**SHEET NO.:** 1 OF 1

**UNIT:** mm [inch]  
**SCALE:** 1:1 **SIZE:** A4